

P-Channel 30-V (D-S) MOSFET
FEATURES

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Portable Devices
- Consumer Electronics

Mechanical

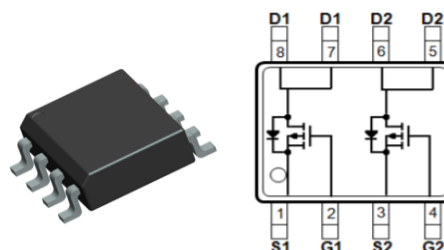
- Case: SOP-8-Dual Package

Packing Information

Package	Packing
SOP-8-Dual	3K/13" Reel

PRODUCTY SUMMARY

V_{DS}	$R_{DS(on)}$ m(Ω)		$I_D(A)$
-30	55	Rdson @-10V	-4.6
	63	Rdson @-4.5V	-4.3
	86	Rdson @-2.5V	-3.7

SOP-8-Dual

Maximum Ratings ($T_A=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current ¹⁾	I_D	-4.6	A
Maximum Power Dissipation	P_D	1.1	W
Pulsed Drain Current ²⁾	I_{DM}	-18.4	A
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^{\circ}C$

Typical Thermal Resistance

Parameter	Symbol	Limit	Unit
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	110	$^{\circ}C/W$

Note:

$R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper

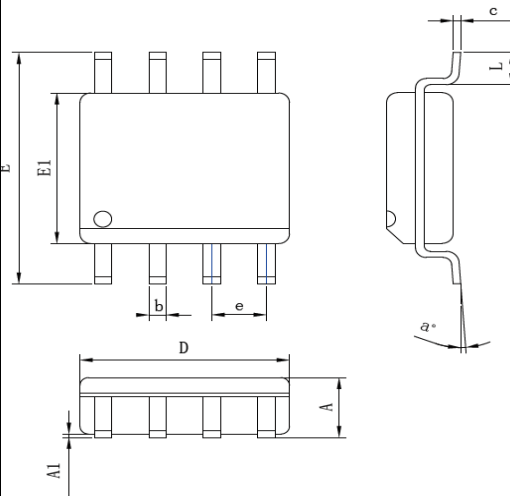
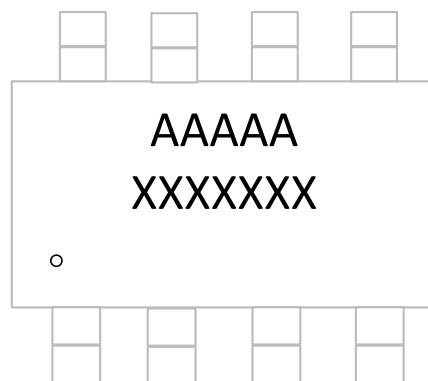
Electrical Characteristics (T _A = 25°C UNLESS OTHERWISE NOTED)						
Characteristics	Symbol	Test Condition	Limits			Unit
			Min	Typ	Max	
Static						
Drain-Source Breakdown Voltage	B _{VDSS}	V _{GS} = 0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.5	-	-1.3	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10.0V, I _D =-4.6A	-	45	55	mΩ
		V _{GS} =-4.5V, I _D =-4.3A	-	52	63	mΩ
		V _{GS} =-2.5V, I _D =-3.7A	-	71	86	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0V	-	-	± 100	nA
Dynamic ³⁾						
Total Gate Charge	Q _g	V _{DS} =-15V, I _D =-5A, V _{GS} =-4.5 (Note 1,2)	-	9.1	-	nC
Gate-Source Charge	Q _{gs}		-	1.8	-	nC
Gate-Drain Charge	Q _{gd}		-	2.6	-	nC
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	816	-	pF
Output Capacitance	C _{oss}		-	64	-	pF
Reverse Transfer Capacitance	C _{rss}		-	42	-	pF
Switching						
Turn-On Delay Time	t _{d(on)}	V _{DD} =-15V, I _D =-5.0A, V _{GS} =-10V, RG=6Ω (Note 1,2)	-	5	-	ns
Turn-On Rise Time	t _r		-	45	-	ns
Turn-Off Delay Time	t _{d(off)}		-	66	-	ns
Turn-Off Fall Time	t _f		-	10	-	ns
Drain-Source Diode						
Diode Forward Voltage	V _{SD}	I _S =-1.0A, V _{GS} =0V	-	-	-1.2	V

NOTES :

1. Pulse width<300us, Duty cycle<2%
2. Essentially independent of operating temperature typical characteristics.
3. RQJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited
5. Guaranteed by design, not subject to production testing

Package Outline Dimensions (inches and millimeters)

SOP-8				
SYMBOL	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A	-	1.75		0.069
A1	0.10	0.23	0.004	0.009
b	0.35	0.48	0.014	0.019
c	0.19	0.25	0.007	0.010
D	4.70	5.10	0.185	0.201
E	5.80	6.20	0.228	0.244
E1	3.70	4.10	0.146	0.161
e	1.27bsc			
L	0.50	0.80	0.020	0.031
a°	0°	8°	0°	8°


Marking Information


First line:

AAAAA = Product number

XXXXXXXX = Tracking number

Third line: Gate Pin Point

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